VACUUMSCHMELZE	SPECIFICATION	Item no.: T60404-N4646-X111
K-No.: 25440	**100 A Current Sensor** For the electronic measurement of currents: DC, AC, pulsed, mixed ..., with a galvanic Isolation between the primary circuit (high power) and the secondary circuit (electronic circuit)	Date: 17.04.2013
Customer: Standard type	Customers Part no.:	Page 1 of 2

Description
- Closed loop (compensation) Current Sensor with magnetic field probe
- Printed circuit board mounting
- Casing and materials UL-listed

Characteristics
- Excellent accuracy
- Very low offset current
- Very low temperature dependency and offset current drift
- Very low hysteresis of offset current
- Short response time
- Wide frequency bandwidth
- Compact design
- Reduced offset ripple

Applications

Mainly used for stationary operation in industrial applications:
- AC variabel speed drives and servo motor drives
- Static converters for for DC motor drives
- Battery supplied applications
- Switched Mode Power Supplies (SMPS)
- Power Supplies for welding applications
- Uninterruptable Power Supllies (UPS)

Electrical data – Ratings

I_{PN}	Primary nominal r.m.s. current	100	A
R_M	Measuring resistance V_C=± 12V	0 ... 200	Ω
	V_C=± 15V	5 … 400	Ω
I_{SN}	Secondary nominal r.m.s. current	50	mA
K_N	Turns ratio	1: 2000	

Accuracy – Dynamic performance data		**min.**	**typ.**	**max.**	**Unit**
$I_{P,max}$	Max. measuring range				
	@ V_C = ±12V, R_M = 5 Ω (t_{max} = 10sec)	±188			A
	@ V_C = ±15V, R_M = 5 Ω (t_{max} = 10sec)	±236			A
X	Accuracy @ I_{PN}, T_A= 25°C		0.1	0.5	%
ε_L	Linearity			0.1	%
I_0	Offset current @ I_P=0, T_A= 25°C		0.02	0.05	mA
t_r	Response time		1		µs
Δt ($I_{P,max}$)	Delay time at di/dt = 100 A/µs		200		ns
f	Frequency bandwidth	DC...200			kHz

General data			**min.**	**typ.**	**max.**	**Unit**
T_A	Ambient operating temperature		-40		+85	°C
T_S	Ambient storage temperature		-40		+90	°C
m	Mass			15		g
V_C	Supply voltage		±11.4	±12 or ±15	±15.75	V
I_C	Current consumption			18		mA
	Constructed and manufactored and tested in accordance with EN 61800-5-1 (primary vs. secondary) Reinforced insulation, Insulation material group 1, Pollution degree 2					
S_{clear}	Clearance (component without solder pad)		12			mm
S_{creep}	Creepage (component without solder pad)		12			mm
V_{sys}	System voltage	overvoltage category 3	RMS		600	V
V_{work}	Working voltage	(table 7 acc. to EN61800-5-1) over voltage category 2	RMS		1000	V
U_{PD}	Rated discharge voltage		peak value		1225	V
	Max. potential difference acc. to UL 508		RMS		600	V_{AC}

Maximale Dauer- und Spitzenströme bei bestimmten Temperaturen

Supply voltage ±12 V:

T_A	85 °C	85 °C	70 °C	55 °C
I_P	100 A	125 A	150 A	150 A
$I_{P,max}$	188 A	183 A	185 A	194 A
R_M	5 Ω	5 Ω	5 Ω	5 Ω

Supply voltage ±15V:

T_A	85 °C	85 °C	70 °C	55 °C
I_P	100 A	125 A	150 A	150 A
$I_{P,max}$	236 A	204 A	232 A	244 A
R_M	5 Ω	20 Ω	5 Ω	5 Ω

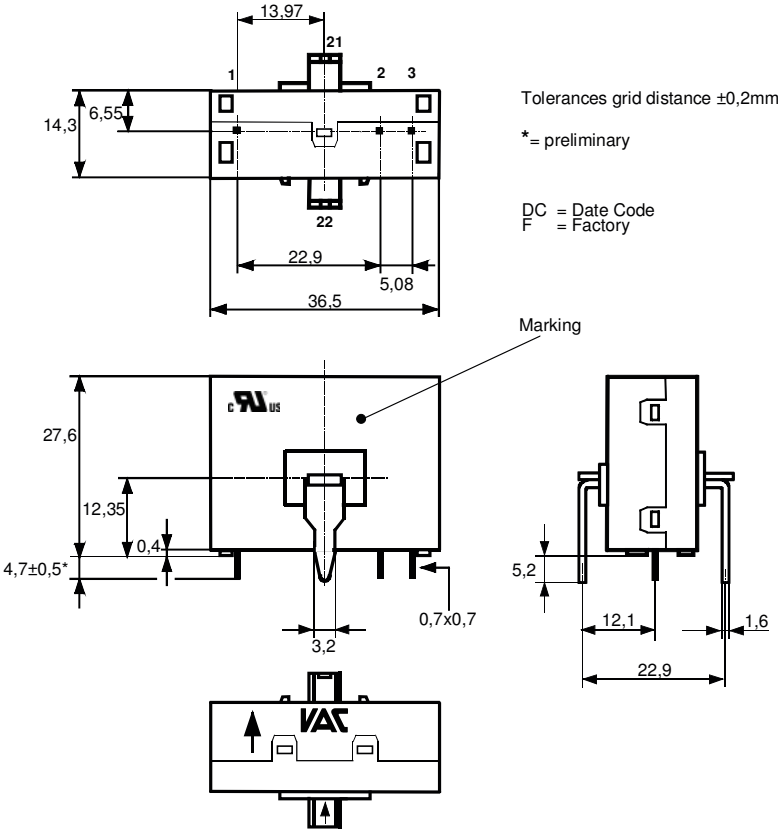
Date	Name	Isuue	Amendment
17.04.13	KRe.	81	Mechnaical outline: marking with UL-sign and max. potential difference acc. to UL 508 added. CN-651
05.02.13	Le	81	Mechanical outline changed (the reference line at the standoff is just a bit down-eccentric). Lapidary change.

Hrsg.: KB-E (editor)	Bearb: Le (designer)		KB-PM IA: KRe. (check)			freig.: HS (released)

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Mechanical outline (mm): General tolerances DIN ISO 2768-c



Connections:

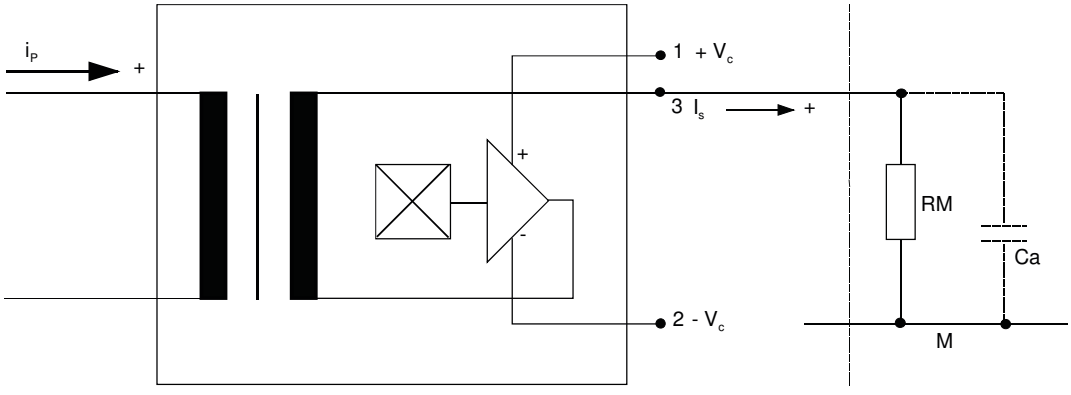
1…3: 0,7 x 0,7 mm

Marking:

UL-sign
4646X111
F DC

Explanation:
DC = Date Code [Format YWW]

Schematic diagram



Temperature of the primary conductor should not exceed 100°C
Additional indications are obtainable on request.
This specification is no declaration of warranty acc. BGB §443 dar.

Hrsg.: KB-E editor	Bearb: Le designer		KB-PM IA: KRe. check			freig.: HS released

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VACUUMSCHMELZE	Additional Information	Item No.: T60404-N4646-X111

K-No.: 25440	**100 A Current Sensor** For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit	Date: 17.04.2013

Customer:	Customers Part No.:	Page 1 of 3

Electrical Data (investigate by a type checking)

		min.	typ.	max.	Unit
V_{Ctot}	Maximum supply voltage (without function) ±15.75 to ±18 V: for 1s per hour			±18	V
R_S	Secondary coil resistance @ T_A=85°C			114	Ω
R_P	Primary resistance @ T_A=25°C		0,1		mΩ
X_{Ti}	Temperature drift of X @ T_A = -40 ... +85 °C			0.1	%
I_{0ges}	Offset current (including I_0, I_{0t}, I_{0T})			0.07	mA
I_{0t}	Long term drift Offset current I_0		0.025		mA
I_{0T}	Offset current temperature drift I_0 @ T_A = -40 ...+85°C		0.025		mA
I_{0H}	Hyteresis current @ I_P=0 (caused by primary current 10 x I_{PN})		0.025	0.05	mA
$\Delta I_0/\Delta V_C$	Supply voltage rejection ratio			0.01	mA/V
i_{oss}	Offset ripple (with1 MHz- filter first order)			0,17	mA
i_{oss}	Offset ripple (with 100 kHz- filter first order)		0.025	0.05	mA
i_{oss}	Offset ripple (with 20 kHz- filter first order)		0.008	0.013	mA
C_k	Maximum possible coupling capacity (primary – secondary)			6	pF

Inspection (Measurement after temperature balance of the samples at room temperature)

$K_N(N_1/N_2)$	(V)	M3011/6	Transformation ratio (I_P=100A, 40-80 Hz)	1 : 2000 ± 0,5	%
I_0	(V)	M3226	Offset current	< 0.05	mA
V_d	(V)	M3014:	Test voltage, rms, 1 s pin 1 – 3 vs. hole	1.8	kV
V_e	(AQL 1/S4)		Partial discharge voltage acc.M3024 (RMS) with V_{vor} (RMS)	1300 1625	V V

Type Testing (Pin 1 - 3 to hole)

V_W	HV transient test according to M3064 (1,2 µs / 50 µs-wave form)		8	kV
V_d	Testing voltage to M3014	(5 s)	3,6	kV
V_e	Partial discharge voltage acc.M3024 (RMS) with V_{vor} (RMS)		1300 1625	V V

Datum	Name	Index	Amendment
17.04.13	Le	81	Applicable documents: Further standards added. CN-651
05.02.13	Le	81	Date updated.

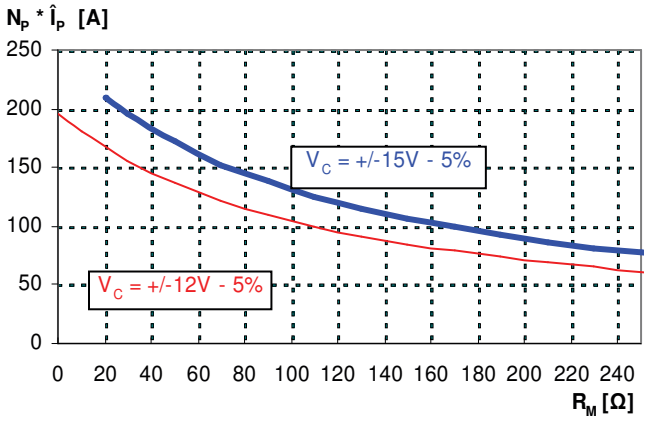
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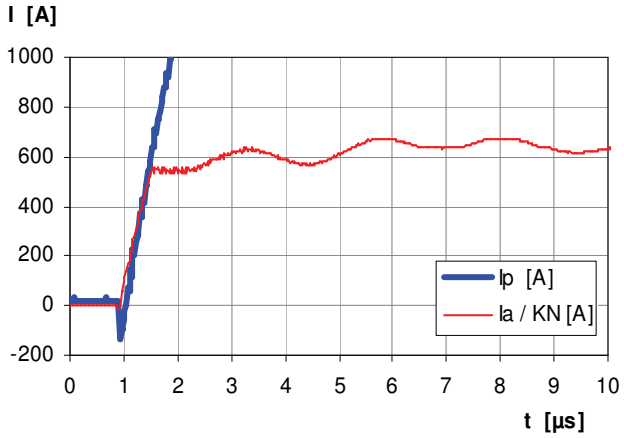
Limit curve of measurable current $\hat{I}_P(R_M)$

@ ambient temperature ≤ 85 °C



Maximum measuring range (µs-range)

Output current behaviour of a 3kA current pulse
@ V_C = ±15V und R_M= 100Ω



Fast increasing currents (higher than the specified $I_{p,max}$), e.g. in case of a short circuit, can be transmitted because the currents are transformed directly and be limited by diodes only.

The offset ripple can be reduced by an external low pass. Simplest solution is a passive low pass filter of 1st order with

$$f_g = \frac{1}{2\pi \cdot R_M \cdot C_a}$$

In this case the response time is enlarged.
It is calculated from:

$$t_r' \le t_r + 2{,}5 R_M C_a$$

Applicable documents

Current direction: A positive output current appears at point I_S, by primary current in direction of the arrow.
Further standards UL 508 ; file E317483, category NMTR2 / NMTR8

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Explanation of several of the terms used in the tablets (in alphabetical order)

I_{0H}: Zero variation after overloading with a DC of tenfold the rated value ($R_M = R_{MN}$)

I_{0t}: Long term drift of I_o after 100 temperature cycles in the range -40 bis 85 °C.

t_r: Response time, measured as delay time at $I_P = 0{,}8 \cdot I_{Pmax}$ between a rectangular current and the output current.

$\Delta t\ (I_{Pmax})$: Delay time between I_{Pmax} and the output current i_a with a primary current rise of $di_1/dt = 100$ A/µs.

U_{PD} Rated discharge voltage (recurring peak voltage separated by the insulation) proved with a sinusoidal voltage V_e

$U_{PD} = \sqrt{2} * V_e / 1{,}5$

V_{vor} Defined voltage is the RMS valve of a sinusoidal voltage with peak value of 1,875 * U_{PD} required for partial discharge test in IEC 61800-5-1

$V_{vor} = 1{,}875 * U_{PD} / \sqrt{2}$

V_{sys} System voltage RMS value of rated voltage according to IEC 61800-5-1

V_{work} Working voltage voltage according to IEC 61800-5-1 which occurs by design in a circuit or across insulation

$X_{ges}(I_{PN})$: The sum of all possible errors over the temperature range by measuring a current I_{PN}:

$$X_{ges} = 100 \cdot \left| \frac{I_S(I_{PN})}{K_N \cdot I_{SN}} - 1 \right|$$

X: Permissible measurement error in the final inspection at RT, defined by

$$X = 100 \cdot \left| \frac{I_{SB}}{I_{SN}} - 1 \right|$$

where I_{SB} is the output DC value of an input DC current of the same magnitude as the (positive) rated current ($I_o = 0$)

X_{Ti}: Temperature drift of the rated value orientated output term. I_{SN} (cf. Notes on F_i) in a specified temperature range, obtained by:

$$X_{Ti} = 100 \cdot \left| \frac{I_{SB}(T_{A2}) - I_{SB}(T_{A1})}{I_{SN}} \right|$$

ε_L: Linearity fault defined by $\varepsilon_L = 100 \cdot \left| \frac{I_P}{I_{PN}} - \frac{I_{Sx}}{I_{SN}} \right|$

Where I_P is any input DC and I_{Sx} the corresponding output term. I_{SN}: see notes of F_i ($I_o = 0$).

This “Additional information“ is no declaration of warranty according BGB §443.

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